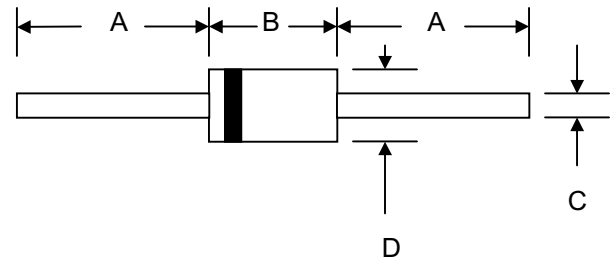


**Data Sheet 2628 Rev. B**

**Features**

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability



**Mechanical Data**

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number

DO-201AD		
Dim	Min	Max
A	1.000(25.40)	—
B	0.334(8.50)	0.374(9.50)
C	0.047(1.20)	0.051(1.30)
D	0.197(5.00)	0.220(5.60)
All Dimensions in inch (mm)		

**Maximum Ratings and Electrical Characteristics** @ $T_A=25^{\circ}\text{C}$  unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	SF51	SF52	SF53	SF54	SF55	SF56	SF57	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	600	V
Working Peak Reverse Voltage	$V_{RWM}$								
DC Blocking Voltage	$V_R$								
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	210	280	420	V
Average Rectified Output Current (Note 1) @ $T_A = 50^{\circ}\text{C}$	$I_o$	5.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	150							A
Forward Voltage @ $I_F = 5.0\text{A}$	$V_{FM}$	0.95			1.3		1.7		V
Peak Reverse Current @ $T_A = 25^{\circ}\text{C}$ At Rated DC Blocking Voltage @ $T_A = 150^{\circ}\text{C}$	$I_{RM}$	5.0			5.0		250		$\mu\text{A}$
		150							
Reverse Recovery Time (Note 2)	$t_{rr}$	35							nS
Typical Junction Capacitance (Note 3)	$C_j$	110			50				pF
Operating Temperature Range	$T_j$	-65 to +175							$^{\circ}\text{C}$
Storage Temperature Range	$T_{STG}$	-65 to +175							$^{\circ}\text{C}$

**\*Glass passivated forms are available upon request**

- Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case  
2. Measured with  $I_F = 0.5\text{A}$ ,  $I_R = 1.0\text{A}$ ,  $I_{RR} = 0.25\text{A}$ . See figure 5.  
3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

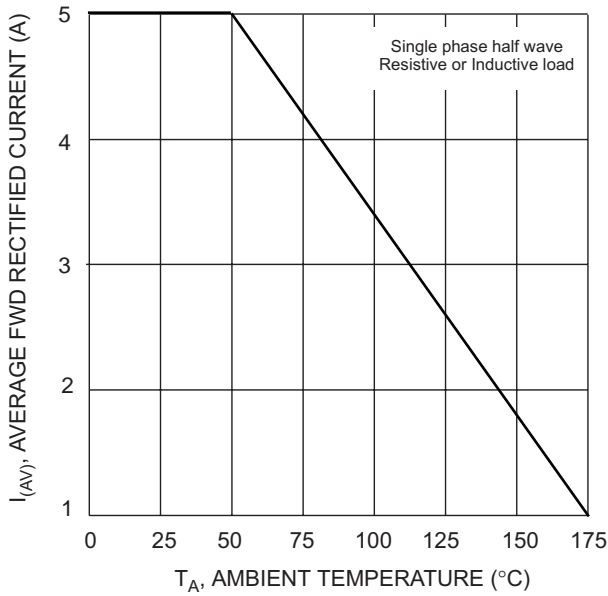


Fig. 1 Forward Current Derating Curve

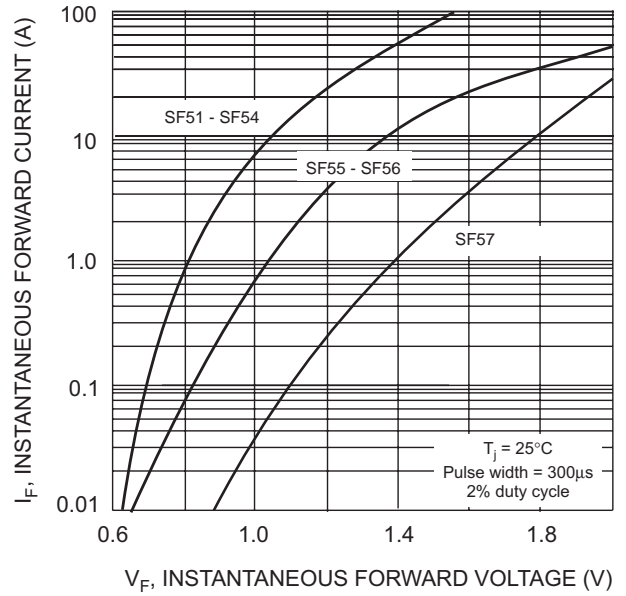


Fig. 2 Typical Forward Characteristics

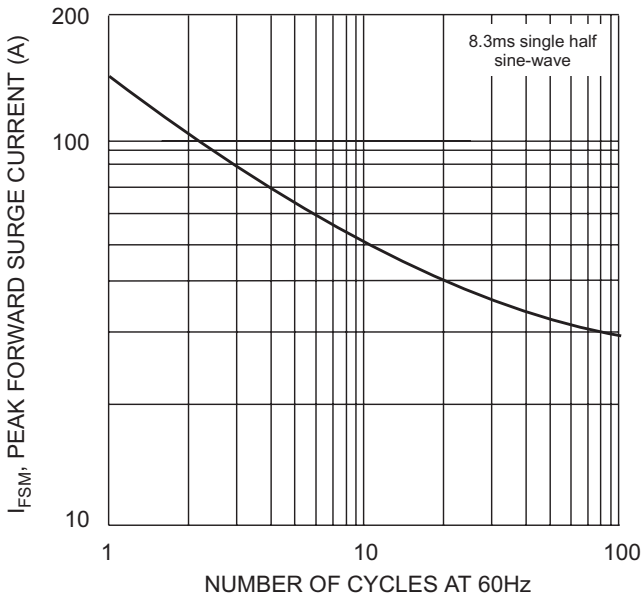


Fig. 3 Peak Forward Surge Current

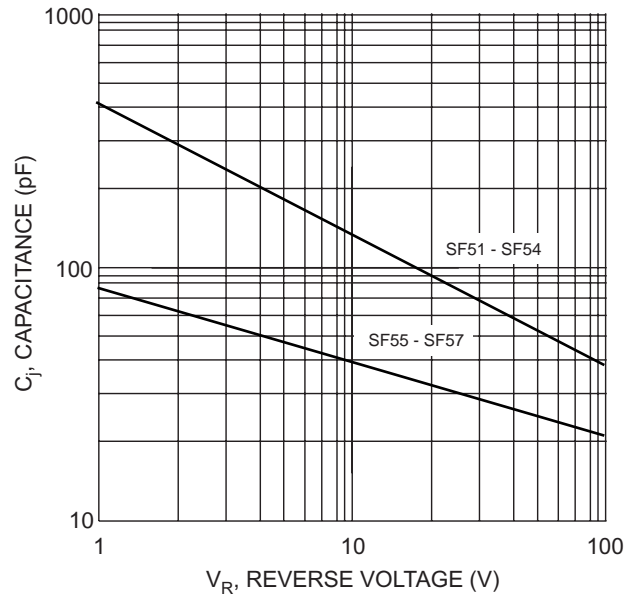
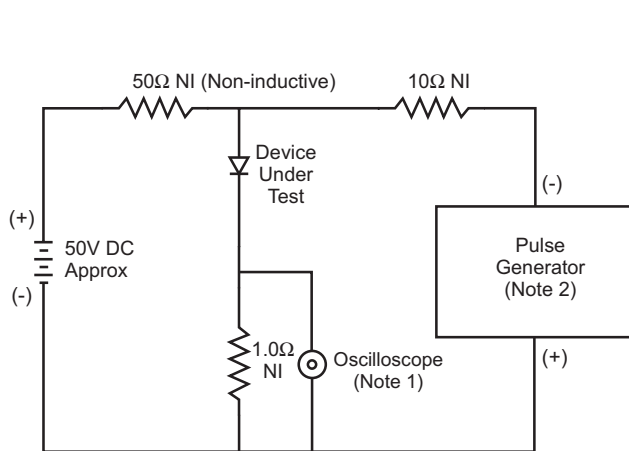
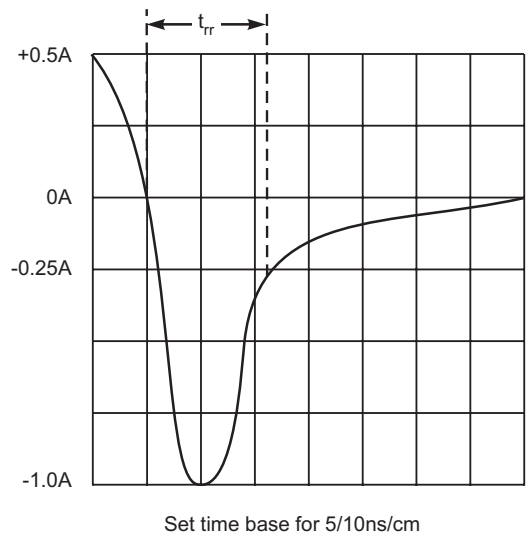


Fig. 4 Typical Junction Capacitance



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
  2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

**TECHNICAL DATA**

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